

# PIN DIODE

UM6000 SERIES  
UM6200 SERIES  
UM6600 SERIES

## Features

- Capacitance specified as low as 0.4 pF (UM6600)
- Resistance specified as low as 0.4Ω (UM6200)
- Voltage ratings to 1000V
- Power dissipation to 6W

## Description

These series of PIN diodes are designed for applications requiring small package size and moderate average power handling capability. The low capacitance of the UM6000 and UM6600 allows them to be used as series switching elements to 1 GHz. The low resistance of the UM6200 is useful in applications where forward bias current must be minimized.

Because of its thick I-region width and long lifetime the UM6000 and UM6600 have been used in distortion sensitive and high peak power applications, including receiver protectors, TACAN, and IFF equipment. Their low capacitance allows them to be useful as attenuator diodes at frequencies greater than 1 GHz. The UM6200 has been used suc-

cessfully in switches in which low insertion loss at low bias current is required.

The "A" style package for this series is the smallest Microsemi PIN diode package. It has been used successfully in many microwave applications using coaxial, microstrip, and stripline techniques at frequencies beyond X-Band. The "B" and "E" style, leaded packages offer the highest available power dissipation for a package this small. They have been used extensively as series switch elements in microstrip circuits. The "C" style package duplicates the physical outline available in conventional ceramic-metal packages but incorporates the many reliability advantages of the Microsemi construction.

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## MAXIMUM RATINGS

### Average Power Dissipation and Thermal Resistance Ratings

| Package           | Condition   | UM6000<br>UM6600 |        | UM6200         |          |
|-------------------|---|------------------|--------|----------------|----------|
|                   |   | P <sub>o</sub>   | θ      | P <sub>o</sub> | θ        |
| A&C               | 25°C Pin Temperature                                | 6W               | 25°C/W | 4W             | 37.5°C/W |
| B&E (Axial Leads) | ½ in. (12.7mm) Total Lead Length<br>to 25°C Contact | 2.5W             | 60°C/W | 2.0W           | 75°C/W   |
| B&E (Axial Leads) | Free Air  | 0.5W             | —      | 0.5W           | —        |

### Peak Power Dissipation Rating

|              |  |                                  |                |
|--------------|--|----------------------------------|----------------|
| All Packages | 1 μs Pulse (Single)<br>at 25°C Ambient | UM6000 - 25 KW<br>UM6200 - 10 KW | UM6600 - 13 KW |
|--------------|--|----------------------------------|----------------|

Operating and Storage Temperature Range: -65°C to +175°C

**Microsemi Corp.**  
**Watertown**  
*The diode experts*

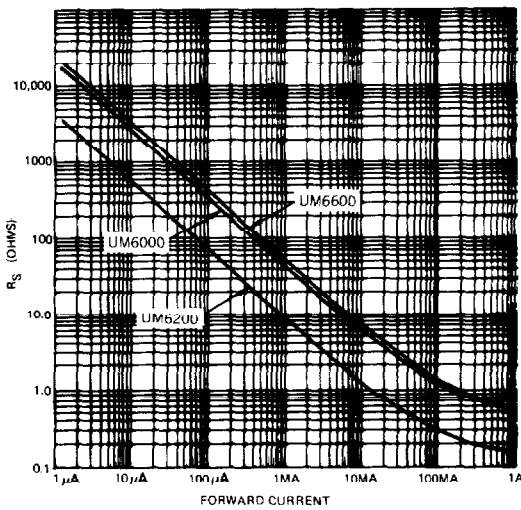
Voltage Ratings (25 °C)

| Reverse Voltage ( $V_R$ ) — Volts<br>( $I_R = 10 \mu A$ ) | Types  |        |        |
|---|--------|--------|--------|
| 100V  | UM6001 | UM6201 | UM6601 |
| 200V  | UM6002 | UM6202 | UM6602 |
| 400V  | —      | UM6204 | —      |
| 600V  | UM6006 | —      | UM6606 |
| 1000V   | UM6010 | —      | UM6610 |

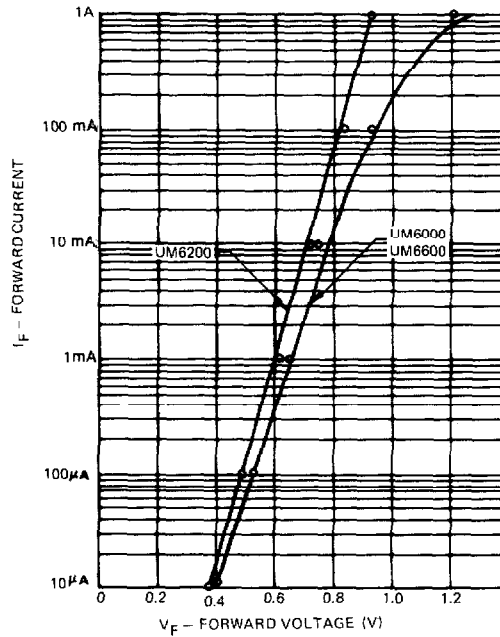
Electrical Specifications (25 °C)

| Test                      | Symbol | UM6600 | UM6000 | UM6200 | Conditions            |
|---------------------------|--------|--------|--------|--------|-----------------------|
| Total Capacitance (Max)   | $C_T$  | 0.4 pF | 0.5 pF | 1.1 pF | 100V, 1MHz            |
| Series Resistance (Max)   | $R_S$  | 2.5Ω   | 1.7Ω   | 0.4Ω   | 100mA, 100MHz         |
| Parallel Resistance (Min) | $R_P$  | 300 KΩ | 300 KΩ | 350 KΩ | 100V, 100MHz          |
| Carrier Lifetime (Min)    | $\tau$ | 1.0 μs | 1.0 μs | 0.6 μs | $I_F = 10 \text{ mA}$ |
| Reverse Current (Max)     | $I_R$  | 10 μA  | 10 μA  | 10 μA  | $V_R = \text{Rating}$ |
| I-Region Width (Min)      | W      | 150 μm | 150 μm | 40 μm  | —                     |

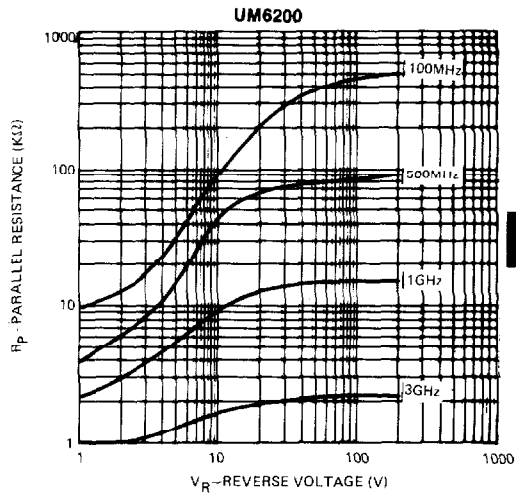
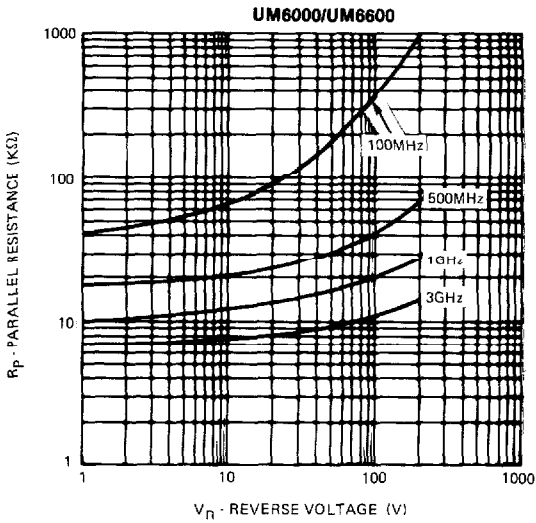
TYPICAL SERIES RESISTANCE VS FORWARD CURRENT (F = 100MHz)



DC CHARACTERISTICS FORWARD VOLTAGE VS CURRENT

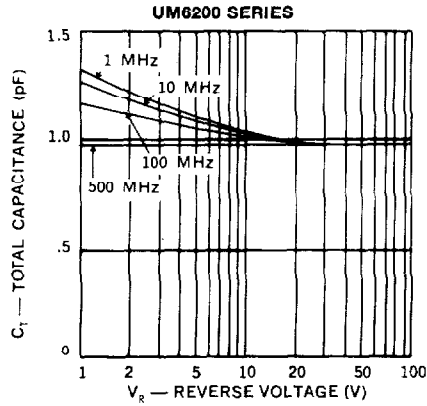
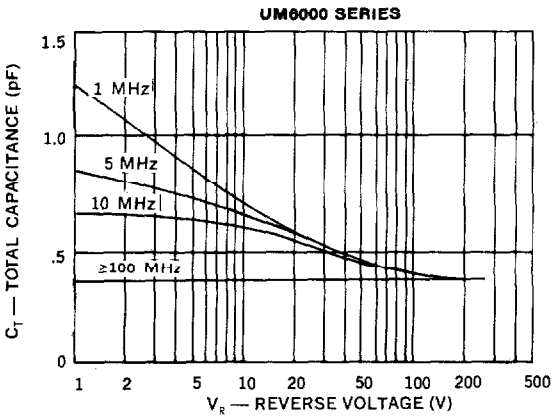


TYPICAL  $R_p$  VS VOLTAGE & FREQUENCY



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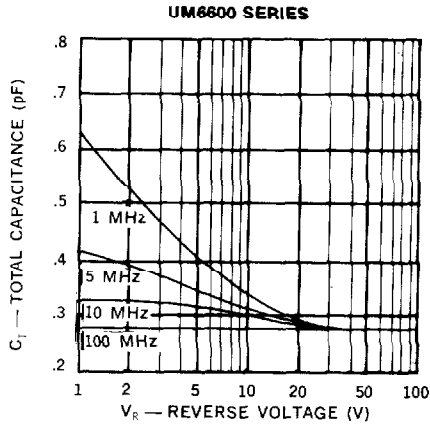
TYPICAL CAPACITANCE VS VOLTAGE AND FREQUENCY



ORDERING INSTRUCTIONS

Part numbers of Microsemi PIN Diodes consist of the letters UM followed by four digits and one or two letters. The first two digits indicate the diode series, the next two digits specify the minimum breakdown voltage in hundreds of volts. The remaining letters denote the package style. Reverse polarity (anode large end cap) is available for the C style and denoted by adding second letter R.

For Example: UM [60][06][CR]  
 [Series 6000] [600 Volts] [Style C|Reverse Polarity]



POWER RATING — AXIAL LEADED DIODE

